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Sheet	1	of	1

Substitute Form PTO-1449 (Modified)

U.S. Decement of Commerce

Attorney's Docket No. 05770-198001

Application No. 10/624,026

Information Disclosure Statement by Applicant (Use several sheets if necessary) Applicant
Malozemoff et

Malozemoff et al.

Filing Date
July 21, 2003

Group Art Unit 2831

(37 CFR §1.98(b))

	U.S. Patent Documents									
Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate			

	Foreign Patent Documents or Published Foreign Patent Applications											
Examiner	Desig.	Document	Publication	Country or			Trans	slation				
Initial	ID	Number	Date	Patent Office	Class	Subclass	Yes	No				
YS	AA	WO 01/08233	2/1/2001	PCT								

	Other Documents (include Author, Title, Date, and Place of Publication)							
Examiner Initial	Desig. ID	Document						
2 Y	AB	D.T. Verebelyi et al., "Uniform performance of continuously processed MOD-YBCO-coated conductors using a textured Ni-W substrate," Superconductor Sci. Technol. 16 (2003) L19-L22.						
YS	AC	R. Nemetschek et al., "Continuous YBa ₂ Cu ₃ O ₇ -tape deposition by thermal evaporation," Physica C 372-376 (2002) 880-882.						
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Y S	AE	Partial International Search Report received in PCT/US2004/021594, mailed June 29, 2005.						

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Date Considered

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Substitute Disclosure Form (PTO-1449)

Sepsitule Form PTO-1449	U.S. Department of Commerce Patent and Trademark Office	Attomey's Docket No. 05770-198001	Application No. 10/624,026	
1 19 2.1	closure Statement oplicant	Applicant Malozemoff et al.		
(Use several si	neets if necessary)	Filing Date July 21, 2003	Group Art Unit 2831	

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YS.	AJ	5,866,252	02/02/1999	de Rochemont et al.						
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Substitute Form PTO-1449

U.S. Department of Commerce Patent and Trademark Office Attomey's Docket No. 05770-198001 Applicant

Application No. 10/624,026

Informati n Disclosure Statem nt by Applicant (Use several sheets if necessary)

Malozemoff et al.

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Group Art Unit

July 21, 2003 2831

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YS	AII	WO 99/35083	07/15/1999	PCT (abstract only)							
Ϋ́ς	AJJ	WO 99/25908	05/27/1999	PCT							
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0	Information Disc by Ap	closure Statement	Applicant Malozemoff et al.		
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Examiner	Desig.	Document	Publication	Country or			Trans	lation			
Initial	OI D	Number	Date	Patent Office	Class	Subclass	Yes	No			
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(Use several sh	eets if necessary)	Filing Date July 21, 2003	Group Art Unit 2831	

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